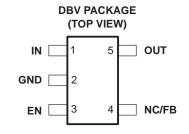


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- 150-mA Low-Dropout Regulator
- Output Voltage: 5 V, 3.8 V, 3.3 V, 3.0 V, 2.8 V,
   2.7 V, 2.5 V, 1.8 V, 1.6 V and Variable
- Dropout Voltage, Typically 300 mV at 150 mA
- Thermal Protection
- Over Current Limitation
- Less Than 2-μA Quiescent Current in Shutdown Mode
- -40°C to 125°C Operating Junction Temperature Range
- 5-Pin SOT-23 (DBV) Package



## description

The TPS763xx family of low-dropout (LDO) voltage regulators offers the benefits of low-dropout voltage, low-power operation, and miniaturized packaging. These regulators feature low dropout voltages and quiescent currents compared to conventional LDO regulators. Offered in a 5-terminal, small outline integrated-circuit SOT-23 package, the TPS763xx series devices are ideal for cost-sensitive designs and for applications where board space is at a premium.

A combination of new circuit design and process innovation has enabled the usual pnp pass transistor to be replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the dropout voltage is very low—typically 300 mV at 150 mA of load current (TPS76333)—and is directly proportional to the load current. Since the PMOS pass element is a voltage-driven device, the quiescent current is very low (140  $\mu$ A maximum) and is stable over the entire range of output load current (0 mA to 150 mA). Intended for use in portable systems such as laptops and cellular phones, the low-dropout voltage feature and low-power operation result in a significant increase in system battery operating life

The TPS763xx also features a logic-enabled sleep mode to shut down the regulator, reducing quiescent current to 1  $\mu$ A maximum at T<sub>J</sub> = 25°C.The TPS763xx is offered in 1.6-V,1.8-V, 2.5-V, 2.7-V, 2.8-V, 3.0-V, 3.3-V, 3.8-V, and 5-V fixed-voltage versions and in a variable version (programmable over the range of 1.5 V to 6.5 V.

#### **AVAILABLE OPTIONS**

TJ	VOLTAGE	PACKAGE	PART N	UMBER	SYMBOL
	Variable		TPS76301DBVT <sup>(1)</sup>	TPS76301DBVR <sup>(2)</sup>	PAZI
	1.6 V		TPS76316DBVT	TPS76316DBVR	PBHI
	1.8 V		TPS76318DBVT	TPS76318DBVR	PBAI
	2.5 V	5 V TPS76325DBVT		TPS76325DBVR	PBBI
4000 1- 40500	2.7 V	SOT-23	TPS76327DBVT	TPS76327DBVR	PBCI
-40°C to 125°C	2.8 V	(DBV)	TPS76328DBVT	TPS76328DBVR	PBDI
	3.0 V	3.0 V TPS76330DBV1		TPS76330DBVR	PBII
	3.3 V		TPS76333DBVT	TPS76333DBVR	PBEI
	3.8 V		TPS76338DBVT	TPS76338DBVR	PBFI
	5.0 V		TPS76350DBVT	TPS76350DBVR	PBGI

<sup>(1)</sup> The DBVT passive indicates tape and reel of 250 parts.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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<sup>(2)</sup> The DBVR passive indicates tape and reel of 3000 parts.

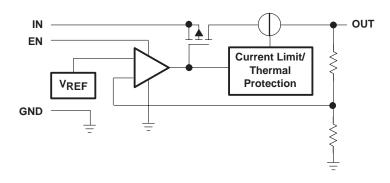


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## **FUNCTIONAL BLOCK DIAGRAM**

# TPS76301 IN Current Limit/ Thermal Protection FB

## TPS76316/ 18/ 25/ 27/ 28/ 30/ 33/ 38/ 50



## **Terminal Functions**

TERMINAL	DECORPTION
NAME	DESCRIPTION
GND	Ground
EN	Enable input
FB	Feedback voltage (TPS76301 only)
IN	Input supply voltage
NC	No connection (fixed-voltage option only)
OUT	Regulated output voltage



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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>1</sup>

Input voltage range <sup>(2)</sup>	0.3 V to 10 V
Voltage range at EN	$\dots$ -0.3 V to V <sub>I</sub> + 0.3 V
Voltage on OUT, FB	
Peak output current	Internally limited
ESD rating, HBM	2 kV
Continuous total power dissipation	See Dissipation Rating Tables
Operating junction temperature range, T <sub>J</sub>	–40°C to 150°C
Storage temperature range, T <sub>stg</sub>	65°C to 150°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### **DISSIPATION RATING TABLE**

BOARD	PACKAGE	$R_{ heta}$ JC	$R_{ heta JA}$	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	$T_A \le 25^{\circ}C$ POWER RATING	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 85°C POWER RATING
Low K <sup>(1)</sup>	DBV	65.8 °C/W	259 °C/W	3.9 mW/°C	386 mW	212 mW	154 mW
High K <sup>(2)</sup>	DBV	65.8 °C/W	180 °C/W	5.6 mW/°C	555 mW	305 mW	222 mW

<sup>(1)</sup> The JEDEC Low K (1s) board design used to derive this data was a 3 inch x 3 inch, two layer board with 2 ounce copper traces on top of the board.

recommended operating conditions

	MIN	NOM MAX	UNIT
Input voltage, V <sub>I</sub> (1)	2.7	10	V
Continuous output current, IO	0	150	mA
Operating junction temperature, T <sub>J</sub>	-40	125	°C

<sup>(1)</sup> To calculate the minimum input voltage for your maximum output current, use the following equation:

<sup>(2)</sup> All voltage values are with respect to network ground terminal.

<sup>(2)</sup> The JEDEC High K (2s2p) board design used to derive this data was a 3 inch x 3 inch, multilayer board with 1 ounce internal power and ground planes and 2 ounce copper traces on top and bottom of the board.

 $V_{I(min)} = V_{O(max)} + V_{DO(max load)}$ 



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electrical characteristics over recommended operating free-air temperature range,  $V_I = V_{O(tvp)} + 1 \text{ V}$ ,  $I_O = 1 \text{ mA}$ , EN = IN,  $C_O = 4.7 \, \mu\text{F}$  (unless otherwise noted)

$V_I = V_{O(typ)} + 1 V, I_O = 1 MA, EN$ PARAMETER			ONDITIONS	MIN	TYP	MAX	UNIT			
			$3.25 \text{ V} > \text{V}_{\text{I}} \ge 2.7 \text{ V},$ $2.5 \text{ V} \ge \text{V}_{\text{O}} \ge 1.5 \text{ V},$	$I_O = 1 \text{ mA to } 75 \text{ mA},$ $T_J = 25^{\circ}\text{C}$	0.98V <sub>O</sub>	VO	1.02 V <sub>O</sub>			
			$3.25 \text{ V} > \text{V}_{\text{I}} \ge 2.7 \text{ V},$ $2.5 \text{ V} \ge \text{V}_{\text{O}} \ge 1.5 \text{ V}$	$I_O = 1 \text{ mA to } 75 \text{ mA},$	0.97V <sub>O</sub>	٧o	1.03V <sub>O</sub>			
		TD070004	$V_1 \ge 3.25 \text{ V},$ $5 \text{ V} \ge V_0 \ge 1.5 \text{ V}$	$I_{O} = 1 \text{ mA to } 100 \text{ mA},$ $T_{J} = 25^{\circ}\text{C}$	0.98V <sub>O</sub>	٧o	1.02V <sub>O</sub>			
		TPS76301	$V_{I} \geq 3.25 \text{ V},$ $5 \text{ V} \geq V_{O} \geq 1.5 \text{ V}$	$I_O = 1$ mA to 100 mA,	0.97V <sub>O</sub>	٧o	1.03 V <sub>O</sub>	V		
			$V_I \geq 3.25 \text{ V}, \\ 5 \text{ V} \geq V_O \geq 1.5 \text{ V}$	$I_O = 1 \text{ mA to } 150 \text{ mA},$ $T_J = 25^{\circ}\text{C}$	0.975V <sub>O</sub>	VO	1.025 V <sub>O</sub>			
			$V_1 \ge 3.25 \text{ V},$ 5 V \ge V_O \ge 1.5 V	$I_O = 1$ mA to 150 mA,	0.9625V <sub>O</sub>	VO	1.0375V <sub>O</sub>			
			V <sub>I</sub> = 2.7 V,	1 mA< $I_O$ < 75 mA, $T_J$ = 25°C	1.568	1.6	1.632			
			V <sub>I</sub> = 2.7 V,	1 mA< I <sub>O</sub> < 75 mA	1.552	1.6	1.648			
		TPS76316	V <sub>I</sub> = 3.25 V,	1 mA < I <sub>O</sub> < 100 mA, T <sub>J</sub> = 25°C	1.568	1.6	1.632	V		
			V <sub>I</sub> = 3.25 V,	1 mA < I <sub>O</sub> < 100 mA	1.552	1.6	1.648			
			V <sub>I</sub> = 3.25 V,	$^{-}$ 1 mA < $I_{O}$ < 150 mA, $T_{J}$ = 25°C	1.560	1.640				
			V <sub>I</sub> = 3.25 V,	1 mA < I <sub>O</sub> < 150 mA	1.536	1.536 1.6 1.664				
		TPS76318	V <sub>I</sub> = 2.7 V,	1 mA< I <sub>O</sub> < 75 mA, T <sub>J</sub> = 25°C	1.764	1.8	1.836			
			V <sub>I</sub> = 2.7 V,	1 mA< I <sub>O</sub> < 75 mA	1.746	1.8	1.854			
VO	Output voltage		V <sub>I</sub> = 3.25 V,	1 mA < I <sub>O</sub> < 100 mA, T <sub>J</sub> = 25°C	1.764	1.8	1.836	V		
			V <sub>I</sub> = 3.25 V,	1 mA < I <sub>O</sub> < 100 mA	1.746	1.8	1.854			
			V <sub>I</sub> = 3.25 V,	1 mA < $I_O$ < 150 mA, $T_J = 25^{\circ}C$	1.755	1.8	1.845			
			V <sub>I</sub> = 3.25 V,	1 mA < I <sub>O</sub> < 150 mA	1.733	1.8	1.867			
			$I_O = 1 \text{ mA to } 100 \text{ mA},$	T <sub>J</sub> = 25°C	2.45	2.5	2.55			
		TDCZCOOL	I <sub>O</sub> = 1 mA to 100 mA		2.425	2.5	2.575			
		TPS76325	$I_O = 1 \text{ mA to } 150 \text{ mA},$	T <sub>J</sub> = 25°C	2.438	2.5	2.562	V		
			$I_O = 1 \text{ mA to } 150 \text{ mA}$		2.407	2.5	2.593			
			$I_O = 1 \text{ mA to } 100 \text{ mA},$	T <sub>J</sub> = 25°C	2.646	2.7	2.754			
		TD070007	I <sub>O</sub> = 1 mA to 100 mA		2.619	2.7	2.781			
		TPS76327	$I_O = 1 \text{ mA to } 150 \text{ mA},$	T <sub>J</sub> = 25°C	2.632	2.7	2.767	V		
			I <sub>O</sub> = 1 mA to 150 mA		2.599	2.7	2.801			
			$I_O = 1 \text{ mA to } 100 \text{ mA},$	T <sub>J</sub> = 25°C	2.744	2.8	2.856			
		TD070000	$I_O = 1 \text{ mA to } 100 \text{ mA}$		2.716	2.8	2.884			
		TPS76328	$I_O = 1 \text{ mA to } 150 \text{ mA},$	T <sub>J</sub> = 25°C	2.73	2.8	2.87	V		
			I <sub>O</sub> = 1 mA to 150 mA		2.695	2.8	2.905	)5		
			$I_O = 1 \text{ mA to } 100 \text{ mA},$	T <sub>J</sub> = 25°C	2.94	2.94 3.0 3.06				
		TDCZCCCC	I <sub>O</sub> = 1 mA to 100 mA		2.91	3.0	3.09	\/		
		TPS76330	I <sub>O</sub> = 1 mA to 150 mA,	T <sub>J</sub> = 25°C	2.925	3.0	3.075	V		
			I <sub>O</sub> = 1 mA to 150 mA		2.888	3.0	3.112			



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## electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(tvp)} + 1 V$ , $I_O = 1 mA$ , EN = IN, $C_O = 4.7 \mu F$ (unless otherwise noted) (continued)

	PARAMETER		TEST COM	NDITIONS	MIN	TYP	MAX	UNIT
			I <sub>O</sub> = 1 mA to 100 mA,	T <sub>J</sub> = 25°C	3.234	3.3	3.366	
		TD07000	I <sub>O</sub> = 1 mA to 100 mA		3.201	3.3	3.399	.,
		TPS76333	I <sub>O</sub> = 1 mA to 150 mA,	3.218	3.3	3.382	V	
			I <sub>O</sub> = 1 mA to 150 mA		3.177	3.3	3.423	
			$I_O = 1$ mA to 100 mA,	T <sub>J</sub> = 25°C	3.724	3.8	3.876	
	Outside at a set to a se	TD070000	I <sub>O</sub> = 1 mA to 100 mA		3.705	3.8	3.895	.,
VO	Output voltage	TPS76338	I <sub>O</sub> = 1 mA to 150 mA,	T <sub>J</sub> = 25°C	3.686	3.8	3.914	V
			I <sub>O</sub> = 1 mA to 150 mA		3.667	3.8	3.933	
			$I_O = 1 \text{ mA to } 100 \text{ mA},$	T <sub>J</sub> = 25°C	4.875	5	5.125	
		TD070050	I <sub>O</sub> = 1 mA to 100 mA	4.825	5	5.175	.,	
		TPS76350	I <sub>O</sub> = 1 mA to 150 mA,	5	5.15	V		
			$I_O = 1 \text{ mA to } 150 \text{ mA}$		4.80	5	5.20	
l.a.	Quiescent current		$I_O = 0$ to 150 mA,	$T_J = 25^{\circ}C$ (1)		85	100	
I(Q)	(GND terminal curre	ent)	I <sub>O</sub> = 0 to 150 mA			140	4	
	Ctondby ourrent		EN < 0.5 V,	T <sub>J</sub> = 25°C		0.5	1	μΑ
	Standby current		EN < 0.5 V				2	
Vn	Output noise voltage	Э	BW = 300 Hz to 50 kHz, $T_J = 25^{\circ}C$ ,	$C_0 = 10 \mu\text{F} (2)$		140		μV
PSRR	Ripple rejection		$f = 1 \text{ kHz}, \ C_0 = 10 \ \mu\text{F},$	$T_J = 25^{\circ}C$ (2)		60		dB
	Current limit		T <sub>J</sub> = 25°C	(3)	0.5	0.8	1.5	Α
	Output voltage line	egulation	$V_{O} + 1 V < V_{I} \le 10 V$	$V_I \ge 3.5 \text{ V},  T_J = 25^{\circ}\text{C}$		0.04	0.07	0/ 1/
	$(\Delta V_O/V_O)$ (see Note 3)		$V_{O} + 1 \ V < V_{I} \le 10 \ V,$	$V_{\parallel} \ge 3.5 \ V$			0.1	%/V
VIH	EN high level input		(2)			1.4	2	V
VIL	EN low level input		(2)		0.5	1.2		V
1.	EN input ourroat		EN = 0 V			-0.01	-0.5	^
1	I <sub>I</sub> EN input current		EN = IN			-0.01	-0.5	μΑ

Line Reg. (mV) = 
$$(\%/V) \times \frac{V_O(V_{lmax} - 3.5 \text{ V})}{100} \times 1000$$
  
If  $V_O > 2.5 \text{ V}$  and  $V_{lmax} = 10 \text{ V}$ ,  $V_{lmin} = V_O + 1 \text{ V}$ :
$$\text{Line Reg. (mV)} = (\%/V) \times \frac{V_O(V_{lmax} - (V_O + 1))}{100} \times 1000$$

<sup>(1)</sup> Minimum IN operating voltage is 2.7 V or  $V_{O(typ)}$  + 1 V, whichever is greater. (2) Test condition includes, output voltage  $V_{O}$ =0 volts (for variable device FB is shorted to  $V_{O}$ ), and pulse duration = 10 mS. (3) If  $V_{O}$  < 2.5 V and  $V_{Imax}$  = 10 V,  $V_{Imin}$  = 3.5 V:

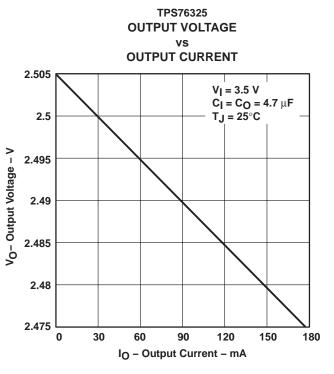


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electrical characteristics over recommended operating free-air temperature range,  $V_I = V_{O(tvp)} + 1 \text{ V}$ ,  $I_O = 1 \text{ mA}$ , EN = IN,  $C_O = 4.7 \mu F$  (unless otherwise noted) (continued)

	$\frac{O(typ) + 1 V, IO = 1 MA}{PARAMETER}$			CONDITIONS	MIN	TYP	MAX	UNIT
			$I_O = 0 \text{ mA},$	T <sub>J</sub> = 25°C		0.2		
		I <sub>O</sub> = 1 mA,	T <sub>J</sub> = 25°C		3			
		I <sub>O</sub> = 50 mA,	T <sub>J</sub> = 25°C		120	150		
		I <sub>O</sub> = 50 mA				200		
	TD070005	I <sub>O</sub> = 75 mA,	T <sub>J</sub> = 25°C		180	225		
		TPS76325	$I_O = 75 \text{ mA}$				300	mV
			I <sub>O</sub> = 100 mA,	T <sub>J</sub> = 25°C		240	300	
			I <sub>O</sub> = 100 mA				400	
			I <sub>O</sub> = 150 mA,	T <sub>J</sub> = 25°C		360	450	
			I <sub>O</sub> = 150 mA				600	
			$I_O = 0 \text{ mA},$	T <sub>J</sub> = 25°C		0.2		
		I <sub>O</sub> = 1 mA,	T <sub>J</sub> = 25°C		3			
		I <sub>O</sub> = 50 mA,	T <sub>J</sub> = 25°C		100	125		
		TPS76333	I <sub>O</sub> = 50 mA				166	mV
.,	Dranavitvaltana		I <sub>O</sub> = 75 mA,	T <sub>J</sub> = 25°C		150	188	
$V_{DO}$	Dropout voltage		I <sub>O</sub> = 75 mA				250	
			I <sub>O</sub> = 100 mA,	T <sub>J</sub> = 25°C		200	250	
			I <sub>O</sub> = 100 mA				333	
			I <sub>O</sub> = 150 mA,	T <sub>J</sub> = 25°C		300	375	
			I <sub>O</sub> = 150 mA				500	
			$I_O = 0 \text{ mA},$	T <sub>J</sub> = 25°C		0.2		
			I <sub>O</sub> = 1 mA,	T <sub>J</sub> = 25°C		2		
			$I_O = 50 \text{ mA},$	T <sub>J</sub> = 25°C		60	75	
			I <sub>O</sub> = 50 mA				100	
		TDCZCOCO	$I_0 = 75 \text{ mA},$	T <sub>J</sub> = 25°C		90	113	>/
		TPS76350	I <sub>O</sub> = 75 mA				150	mV
			I <sub>O</sub> = 100 mA,	T <sub>J</sub> = 25°C		120	150	
			I <sub>O</sub> = 100 mA				200	
			I <sub>O</sub> = 150 mA,	T <sub>J</sub> = 25°C		180	225	
			I <sub>O</sub> = 150 mA				300	

## TYPICAL CHARACTERISTICS



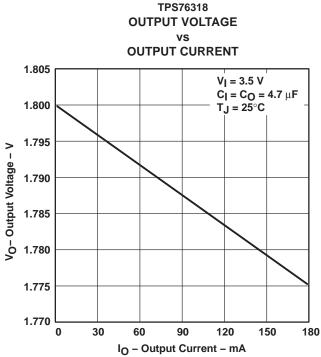
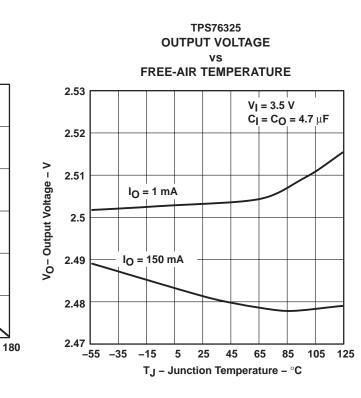


Figure 2

Figure 1

**TPS76350** 

**OUTPUT VOLTAGE** 



VS
OUTPUT CURRENT

5.01

V<sub>I</sub> = 6 V
C<sub>I</sub> = C<sub>O</sub> = 4.7 μF
T<sub>J</sub> = 25°C

A.99

4.98

4.98

4.96

4.95

0

30

60

90

IO - Output Current - mA

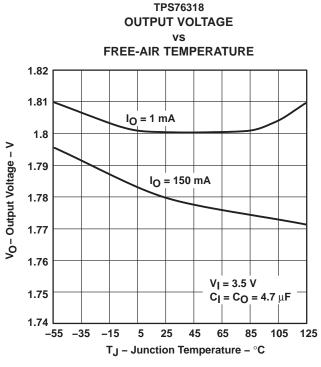
Figure 3 Figure 4

150

120



## TYPICAL CHARACTERISTICS

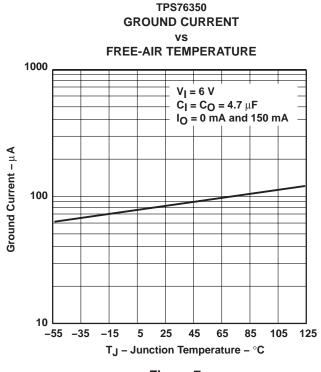


**OUTPUT VOLTAGE** vs FREE-AIR TEMPERATURE 5.1  $V_I = 6 V$ 5.08  $C_{I} = C_{O} = 4.7 \mu F$ 5.06 Vo- Output Voltage - V 5.04 5.02  $I_0 = 1 \text{ mA}$ 5 4.98 4.96  $I_0 = 150 \text{ mA}$ 4.94 4.92 4.9 -55 -35 -15 5 25 45 65 85 105 125 T<sub>J</sub> - Junction Temperature - °C

**TPS76350** 

Figure 5

Figure 6



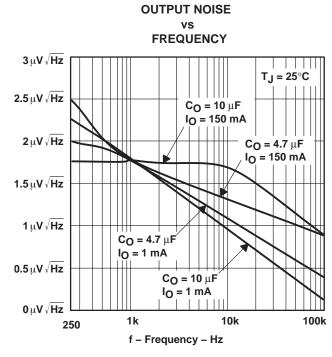


Figure 7

Figure 8



## **TYPICAL CHARACTERISTICS**

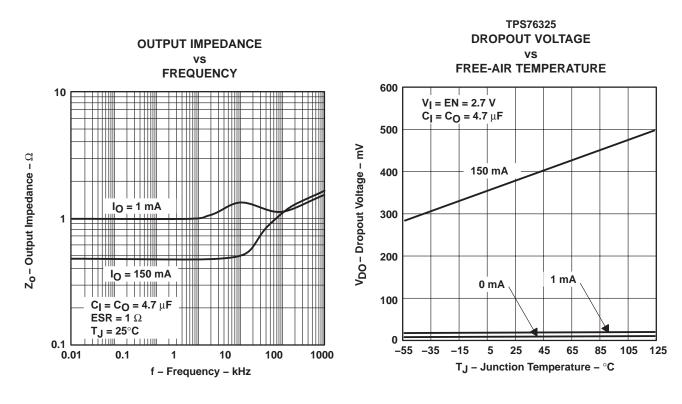
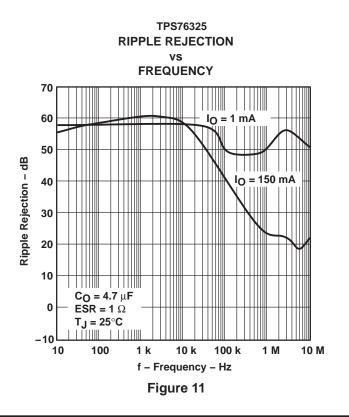
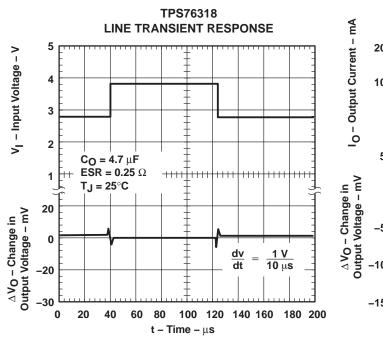


Figure 9 Figure 10





## TYPICAL CHARACTERISTICS



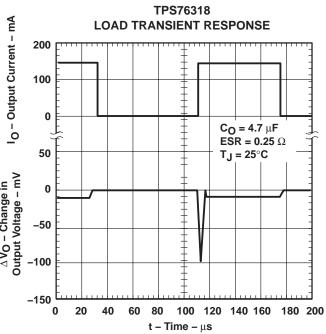


Figure 12

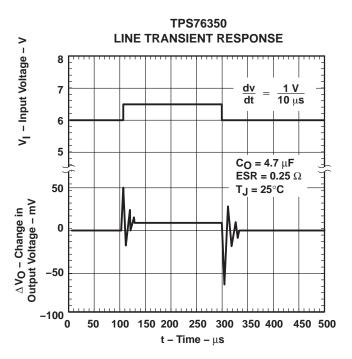


Figure 14

Figure 13

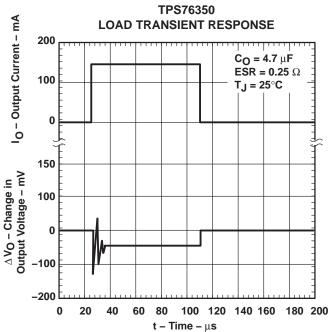


Figure 15

## TYPICAL CHARACTERISTICS

# TYPICAL REGIONS OF STABILITY COMPENSATION SERIES RESISTANCE (CSR)(1)

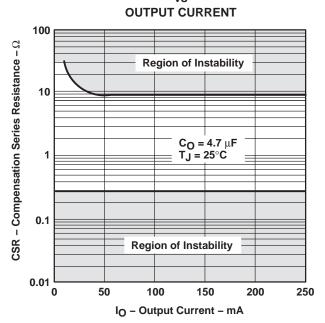


Figure 16

# TYPICAL REGIONS OF STABILITY

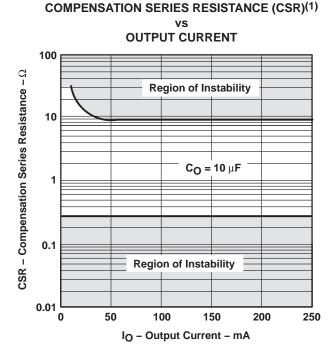


Figure 18

# TYPICAL REGIONS OF STABILITY COMPENSATION SERIES RESISTANCE (CSR)(1)

# ADDED CERAMIC CAPACITANCE

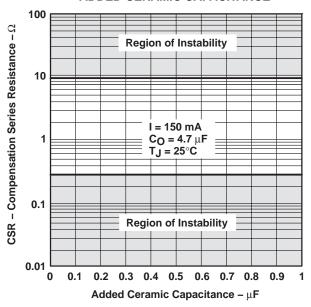


Figure 17

# TYPICAL REGIONS OF STABILITY COMPENSATION SERIES RESISTANCE (CSR)(1)

## ADDED CERAMIC CAPACITANCE

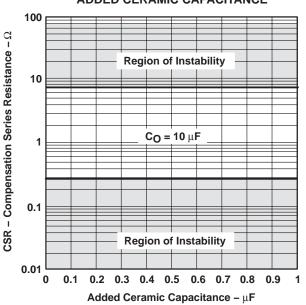


Figure 19

<sup>(1)</sup> CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to CO.

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#### APPLICATION INFORMATION

The TPS763xx low-dropout (LDO) regulators are new families of regulators which have been optimized for use in battery-operated equipment and feature extremely low dropout voltages, low quiescent current (140  $\mu$ A), and an enable input to reduce supply currents to less than 2  $\mu$ A when the regulator is turned off.

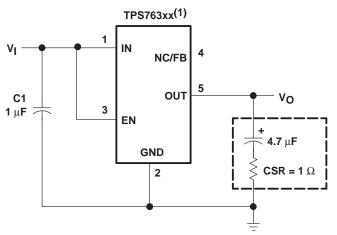
## device operation

The TPS763xx uses a PMOS pass element to dramatically reduce both dropout voltage and supply current over more conventional PNP pass element LDO designs. The PMOS pass element is a voltage-controlled device that, unlike a PNP transistor, does not require increased drive current as output current increases. Supply current in the TPS763xx is essentially constant from no-load to maximum load.

Current limiting and thermal protection prevent damage by excessive output current and/or power dissipation. The device switches into a constant-current mode at approximately 1 A; further load reduces the output voltage instead of increasing the output current. The thermal protection shuts the regulator off if the junction temperature rises above 165°C. Recovery is automatic when the junction temperature drops approximately 25°C below the high temperature trip point. The PMOS pass element includes a back diode that safely conducts reverse current when the input voltage level drops below the output voltage level.

A logic low on the enable input, EN shuts off the output and reduces the supply current to less than 2  $\mu$ A. EN should be tied high in applications where the shutdown feature is not used.

A typical application circuit is shown in Figure 20.



(1) TPS76316, TPS76318, TPS76325, TPS76327, TPS76328, TPS7630 TPS76333, TPS76338, TPS76350 (fixed-voltage options).

Figure 20. Typical Application Circuit

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#### APPLICATION INFORMATION

## external capacitor requirements

Although not required, a  $0.047\,\mu\text{F}$  or larger ceramic bypass input capacitor, connected between IN and GND and located close to the TPS763xx, is recommended to improve transient response and noise rejection. A higher-value electrolytic input capacitor may be necessary if large, fast-rise-time load transients are anticipated and the device is located several inches from the power source.

Like all low dropout regulators, the TPS763xx requires an output capacitor connected between OUT and GND to stabilize the internal loop control. The minimum recommended capacitance value is 4.7  $\mu$ F and the ESR (equivalent series resistance) must be between 0.3  $\Omega$  and 10  $\Omega$ . Capacitor values 4.7  $\mu$ F or larger are acceptable, provided the ESR is less than 10  $\Omega$ . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 4.7  $\mu$ F surface-mount solid tantalum capacitors, including devices from Sprague, Kemet, and Nichico, meet the ESR requirements stated above.

#### CAPACITOR SELECTION

PART NO.	MFR.	VALUE	MAX ESR(1)	SIZE $(H \times L \times W)^{\dagger}$
T494B475K016AS	KEMET	4.7 μF	$1.5~\Omega$	$1.9 \times 3.5 \times 2.8$
195D106x0016x2T	SPRAGUE	10 μF	$1.5~\Omega$	$1.3\times7.0\times2.7$
695D106x003562T	SPRAGUE	10 μF	$1.3~\Omega$	$2.5\times7.6\times2.5$
TPSC475K035R0600	AVX	4.7 μF	$0.6~\Omega$	$2.6\times6.0\times3.2$

<sup>(1)</sup> Size is in mm. ESR is maximum resistance in ohms at 100 kHz and  $T_A = 25^{\circ}$ C. Listings are sorted by height.

## output voltage programming

The output voltage of the TPS76301 adjustable regulator is programmed using an external resistor divider as shown in Figure 21. The output voltage is calculated using:

$$V_{O} = 0.995 \times V_{ref} \times \left(1 + \frac{R1}{R2}\right) \tag{1}$$

Where:

 $V_{ref} = 1.192 \text{ V typ (the internal reference voltage)}$ 

0.995 is a constant used to center the load regulator (1%)

Resistors R1 and R2 should be chosen for approximately 7- $\mu$ A divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = 169 k $\Omega$  to set the divider current at 7  $\mu$ A and then calculate R1 using:

$$R1 = \left(\frac{V_O}{0.995 \times V_{ref}} - 1\right) \times R2 \tag{2}$$

## APPLICATION INFORMATION

# OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	(1.0)(4)					
(V)	R1	R2				
2.5	187	169				
3.3	301	169				
3.6	348	169				
4	402	169				
5	549	169				
6.45	750 169					
(1) 1% values	shown.					

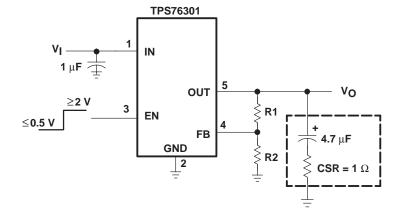


Figure 21. TPS76301 Adjustable LDO Regulator Programming

## power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of  $125^{\circ}$ C; the maximum junction temperature allowable to avoid damaging the device is  $150^{\circ}$ C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation,  $P_{D(max)}$ , and the actual dissipation,  $P_D$ , which must be less than or equal to  $P_{D(max)}$ .

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_{J}max - T_{A}}{R_{\theta JA}}$$

Where:

T<sub>.</sub>Imax is the maximum allowable junction temperature

 $R_{\theta,JA}$  is the thermal resistance junction-to-ambient for the package, see the dissipation rating table.

T<sub>A</sub> is the ambient temperature.

The regulator dissipation is calculated using:

$$\mathsf{P}_\mathsf{D} = \left(\mathsf{V}_\mathsf{I} - \mathsf{V}_\mathsf{O}\right) \times \mathsf{I}_\mathsf{O}$$

Power dissipation resulting from quiescent current is negligible.



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## APPLICATION INFORMATION

## regulator protection

The TPS763xx pass element has a built-in back diode that safely conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage is anticipated, external limiting might be appropriate.

The TPS763xx also features internal current limiting and thermal protection. During normal operation, the TPS763xx limits output current to approximately 800 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 165°C, thermal-protection circuitry shuts it down. Once the device has cooled down to below 140°C, regulator operation resumes.



## **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
TPS76301DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76301DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76301DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76301DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76316DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76316DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76316DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76316DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76318DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76318DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76318DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76318DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76325DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76325DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76325DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76325DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76327DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI
TPS76327DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76327DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76327DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76327DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76328DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI
TPS76328DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76328DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76328DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76328DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS &	CU NIPDAU	Level-1-260C-UNLIM





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Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Packag Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finis	h MSL Peak Temp <sup>(3)</sup>
						no Sb/Br)		
TPS76330DBV	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI
TPS76330DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76330DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76330DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76330DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76333DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76333DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76333DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76333DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76338DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76338DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76338DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76338DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76350DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76350DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76350DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS76350DBVTG4	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

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<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



## PACKAGE OPTION ADDENDUM

27-Feb-2006

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# DBV (R-PDSO-G5)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-178 Variation AA.



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